

30 V, 5.1 A NPN low VCEsat transistor

19 February 2024

Product data sheet

1. General description

NPN low V_{CEsat} transistor in a SOT89 (SC-62/TO-243) small and flat lead Surface-Mounted Device (SMD) plastic package.

PNP complement: PBSS303PX.

2. Features and benefits

- Low collector-emitter saturation voltage V_{CEsat}
- + High collector current capability ${\rm I}_{\rm C}$ and ${\rm I}_{\rm CM}$
- + High collector current gain (h_{FE}) at high I_C
- High efficiency due to less heat generation
- Smaller required Printed-Circuit Board (PCB) area than for conventional transistors
- AEC-Q101 qualified

3. Applications

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- DC-to-DC conversion
- MOSFET gate driving
- Motor control

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- Charging circuits
- Power switches (e.g. motors, fans)

4. Quick reference data

Table 1. Quick r	reference data					
Symbol	Parameter	Conditions	Min	Тур	Max	Unit
V _{CEO}	collector-emitter voltage	open base	-	-	30	V
I _C	collector current		-	-	5.1	А
I _{CM}	peak collector current	single pulse; t _p ≤ 1 ms	-	-	10.2	А
R _{CEsat}	collector-emitter saturation resistance	$I_C = 4$ A; $I_B = 200$ mA; pulsed; $t_p \le 300$ μs; δ ≤ 0.02 ; $T_{amb} = 25$ °C	-	31	44	mΩ

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5. Pinning information

Pin	Symbol	Description	Simplified outline	Graphic symbol
1	E	emitter		С
2	С	collector		
3	В	base		B
			SOT89	sym042

6. Ordering information

Table 3. Ordering information						
Type number	Package					
	Name	Description	Version			
PBSS303NX	SOT89	plastic, surface-mounted package; 3 leads; 1.5 mm pitch; 4.5 mm x 2.5 mm x 1.5 mm body	<u>SOT89</u>			

7. Marking

Table 4. Marking codes

Type number	Marking code[1]
PBSS303NX	%5D

[1] % = placeholder for manufacturing site code

8. Limiting values

Table 5. Limiting values

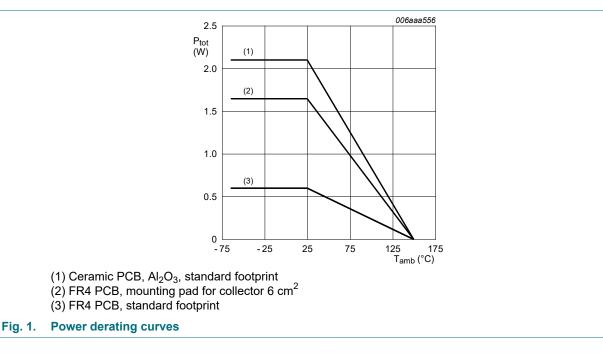
In accordance with the Absolute Maximum Rating System (IEC 60134).

Symbol	Parameter	Conditions		Min	Max	Unit
V _{CBO}	collector-base voltage	open emitter		-	30	V
V _{CEO}	collector-emitter voltage	open base		-	30	V
V _{EBO}	emitter-base voltage	open collector		-	5	V
I _C	collector current			-	5.1	А
I _{CM}	peak collector current	single pulse; t _p ≤ 1 ms		-	10.2	А
P _{tot}	total power dissipation	T _{amb} ≤ 25 °C	[1]	-	0.6	W
			[2]	-	1.65	W
			[3]	-	2.1	W
Tj	junction temperature			-	150	°C
T _{amb}	ambient temperature			-65	150	°C
T _{stg}	storage temperature			-65	150	°C

[1] Device mounted on an FR4 PCB, single-sided copper, tin-plated and standard footprint.

[2] Device mounted on an FR4 PCB, single-sided copper, tin-plated, mounting pad for collector 6 cm².

[3] Device mounted on a ceramic PCB, Al₂O₃, standard footprint.



9. Thermal characteristics

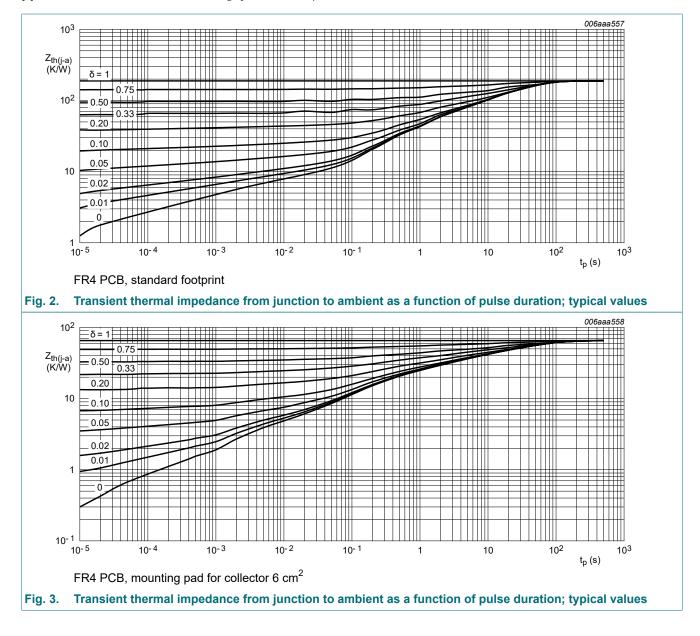
Table 6. Thermal characteristic	Table	6.	Thermal	characteristics
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Symbol	Parameter	Conditions		Min	Тур	Мах	Unit
R _{th(j-a)} thermal resistance from junction to ambient		[1]	-	-	208	K/W	
		[2]	-	-	76	K/W	
			[3]	-	-	60	K/W
R _{th(j-sp)}	thermal resistance from junction to solder point			-	-	20	K/W

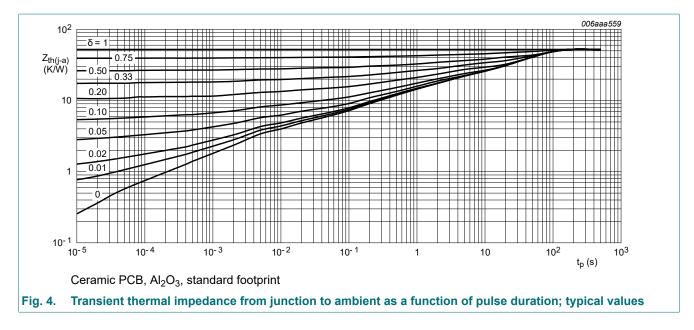
[1] Device mounted on an FR4 PCB, single-sided copper, tin-plated and standard footprint.

[2] Device mounted on an FR4 PCB, single-sided copper, tin-plated, mounting pad for collector 6 cm².

[3] Device mounted on a ceramic PCB, Al₂O₃, standard footprint.



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10. Characteristics

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
СВО	collector-base cut-off	V _{CB} = 30 V; I _E = 0 A; T _{amb} = 25 °C	-	-	100	nA
	current	V _{CB} = 30 V; I _E = 0 A; T _i = 150 °C	-	-	50	μA
ЕВО	emitter-base cut-off current	$V_{EB} = 5 \text{ V}; \text{ I}_{C} = 0 \text{ A}; \text{ T}_{amb} = 25 \text{ °C}$	-	-	100	nA
h _{FE}	DC current gain	V _{CE} = 2 V; I _C = 0.5 A; pulsed; t _p ≤ 300 μs; δ ≤ 0.02; T _{amb} = 25 °C	300	480	-	
		$ \begin{array}{l} V_{CE} = 2 \; V; \; I_{C} = 1 \; A; \; pulsed; \; t_{p} \leq \; 300 \; \mu s; \\ \delta \leq \; 0.02; \; T_{amb} = 25 \; ^{\circ} C \end{array} $	300	460	-	
		$ V_{CE} = 2 \text{ V}; I_C = 2 \text{ A}; \text{ pulsed}; t_p \leq 300 \mu\text{s}; \\ \delta \leq 0.02; T_{amb} = 25 ^\circ\text{C} $	250	430	-	
			200	360	-	
		$ V_{CE} = 2 \text{ V}; I_C = 6 \text{ A}; \text{ pulsed}; t_p \leq 300 \mu\text{s}; \\ \delta \leq 0.02; T_{amb} = 25 ^\circ\text{C} $	180	270	-	
V _{CEsat}	collector-emitter saturation voltage	I_C = 0.5 A; I_B = 50 mA; pulsed; $t_p \le$ 300 μs; δ ≤ 0.02; T_{amb} = 25 °C	-	20	30	mV
		I _C = 1 A; I _B = 50 mA; pulsed; t _p ≤ 300 μs; δ ≤ 0.02; T _{amb} = 25 °C	-	40	60	mV
		I _C = 1 A; I _B = 10 mA; pulsed; t _p ≤ 300 μs; δ ≤ 0.02; T _{amb} = 25 °C	-	60	90	mV
		I _C = 2 A; I _B = 40 mA; pulsed; t _p ≤ 300 μs; δ ≤ 0.02; T _{amb} = 25 °C	-	80	110	mV
		$I_C = 4$ A; $I_B = 200$ mA; pulsed; $t_p \le 300$ μs; δ ≤ 0.02 ; $T_{amb} = 25$ °C	-	125	175	mV
		I_{C} = 4 A; I_{B} = 400 mA; pulsed; $t_{p} \le$ 300 μs; δ ≤ 0.02; T_{amb} = 25 °C	-	120	170	mV
		I_C = 4 A; I_B = 40 mA; pulsed; $t_p \le$ 300 μs; δ ≤ 0.02; T_{amb} = 25 °C	-	160	250	mV
		I_C = 5.1 A; I_B = 255 mA; pulsed; $t_p \le$ 300 μs; δ ≤ 0.02; T_{amb} = 25 °C	-	150	220	mV
R _{CEsat}	collector-emitter saturation resistance	$I_C = 4$ A; $I_B = 200$ mA; pulsed; $t_p \le 300$ μs; δ ≤ 0.02 ; $T_{amb} = 25$ °C	-	31	44	mΩ
		I_C = 4 A; I_B = 40 mA; pulsed; $t_p \le$ 300 μs; δ ≤ 0.02; T_{amb} = 25 °C	-	40	63	mΩ
V _{BEsat}	base-emitter saturation voltage	I_C = 1 A; I_B = 100 mA; pulsed; $t_p \le$ 300 μs; δ ≤ 0.02; T_{amb} = 25 °C	-	0.81	0.9	V
		$I_C = 4$ A; $I_B = 400$ mA; pulsed; $t_p \le 300$ μs; δ ≤ 0.02 ; $T_{amb} = 25$ °C	-	0.95	1.05	V
V _{BEon}	base-emitter turn-on voltage	$ \begin{array}{l} V_{CE} \texttt{= 2 V; } I_{C} \texttt{= 2 A; pulsed; } t_{p} \texttt{\leq } 300 \ \texttt{\mu}\texttt{s}; \\ \delta \texttt{\leq } 0.02; \ T_{amb} \texttt{= 25 °C} \end{array} $	-	0.75	0.85	V
d	delay time	V _{CC} = 12.5 V; I _C = 3 A; I _{Bon} = 0.15 A;	-	15	-	ns
r	rise time	I _{Boff} = -0.15 A; T _{amb} = 25 °C	-	50	-	ns
on	turn-on time]	-	65	-	ns
s	storage time		-	305	-	ns
t _f	fall time		-	70	-	ns
t _{off}	turn-off time		-	375	-	ns

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Symbol	Parameter	Conditions		Min	Тур	Max	Unit
fT	transition frequency	V_{CE} = 10 V; I _C = 0.1 A; f T _{amb} = 25 °C	= 100 MHz;	-	130	-	MHz
Cc	collector capacitance	V _{CB} = 10 V; I _E = 0 A; i _e = T _{amb} = 25 °C	0 A; f = 1 MHz;	-	60	100	pF
1000		006aaa580	14			006aaa586	
h _{FE} 800			(A) 12		IB (n	nA) = 80 	
600			10 8			48 - 40 - 32 - 24	
400						16-	
200			2			8	
0 10 ⁻¹	1 10 10 ²	10 ³ 10 ⁴ I _C (mA)	0 1	2 3		5 V _{CE} (V)	
V _{CE} =			T _{amb} = 25 °C				
	$amb = 100 \degree C$	Fig	6. Collector cur	rent as a fu	unction of	of collec	tor-

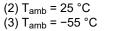
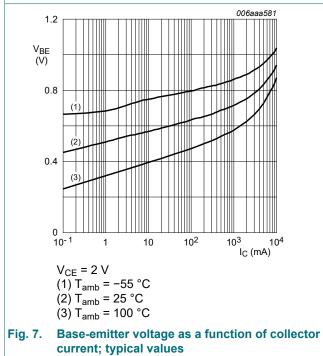


Fig. 5. DC current gain as a function of collector current; typical values





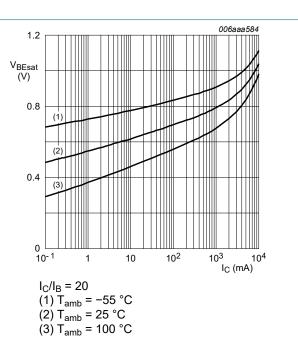
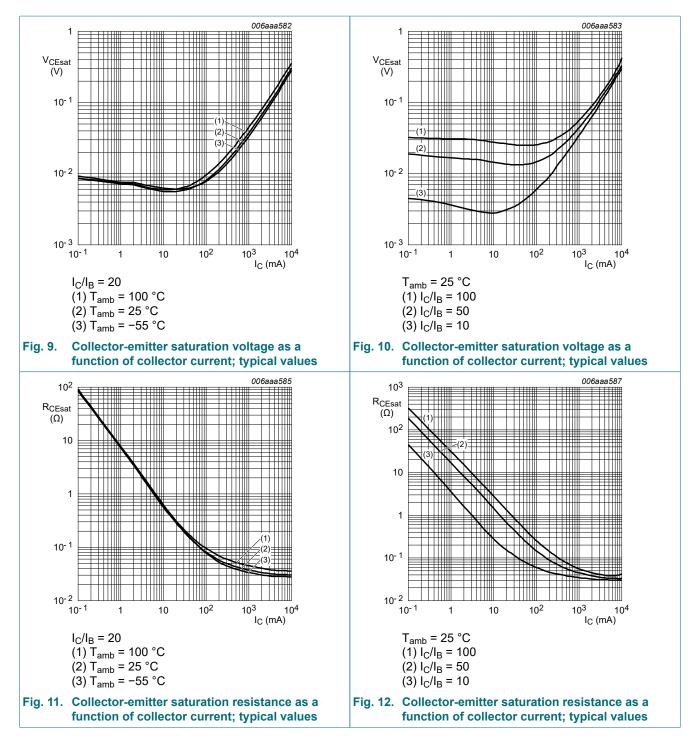


Fig. 8. Base-emitter saturation voltage as a function of collector current; typical values

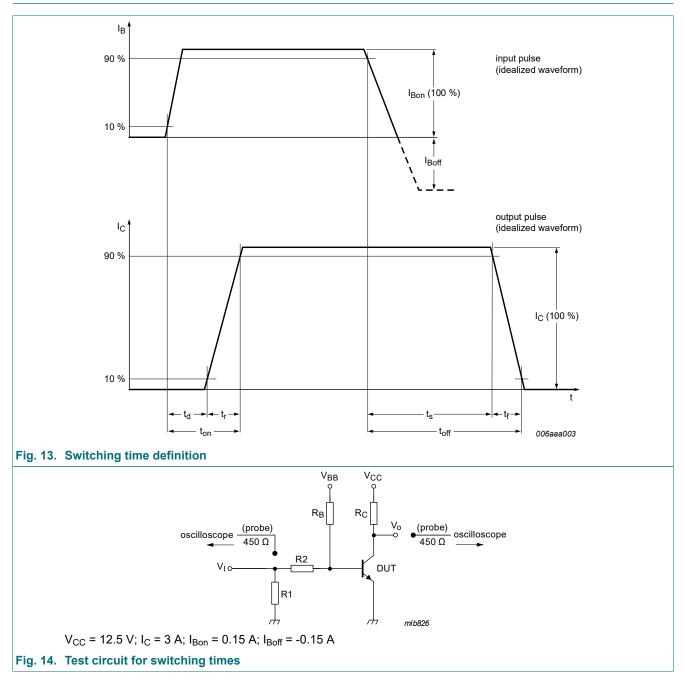
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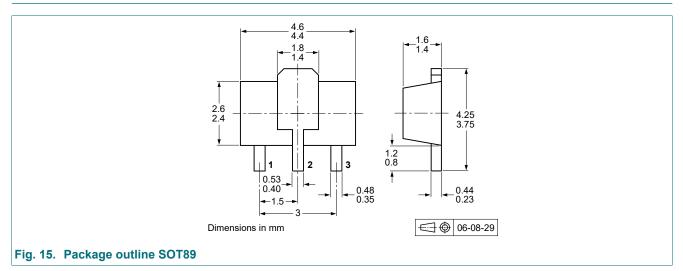
11. Test information



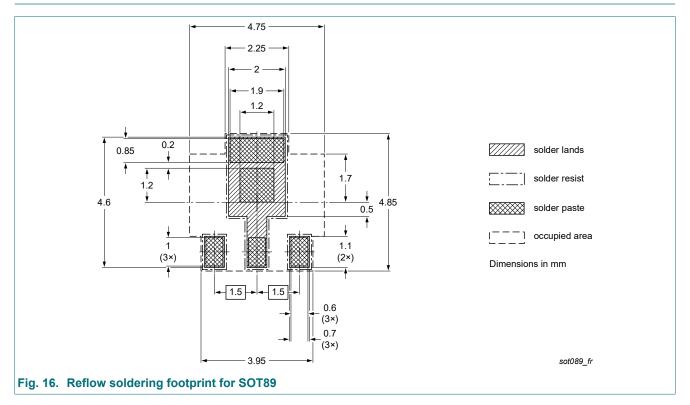
Quality information

This product has been qualified in accordance with the Automotive Electronics Council (AEC) standard *Q101* - *Stress test qualification for discrete semiconductors*, and is suitable for use in automotive applications.

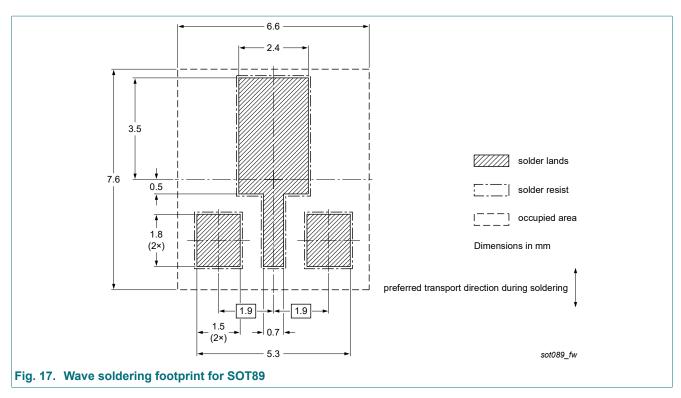
12. Package outline



13. Soldering



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14. Revision history

Table 8. Revision hi	story						
Data sheet ID	Release date	Data sheet status	Change notice	Supersedes			
PBSS303NX v.3	20240219	Product data sheet	-	PBSS303NX_2			
Modifications:	 The format of this data sheet has been redesigned to comply with the identity guidelines of Nexperia. Legal texts have been adapted to the new company name where appropriate. Section "Packing information" removed. 						
PBSS303NX_2	20091120	Product data sheet	-	PBSS303NX_1			
PBSS303NX_1	20060823	Product data sheet	-	-			

15. Legal information

Data sheet status

Document status [1][2]	Product status [3]	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.
Product [short] data sheet	Production	This document contains the product specification.

 Please consult the most recently issued document before initiating or completing a design.

[2] The term 'short data sheet' is explained in section "Definitions".

[3] The product status of device(s) described in this document may have changed since this document was published and may differ in case of multiple devices. The latest product status information is available on the internet at <u>https://www.nexperia.com</u>.

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